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				Application Number		
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STATEMENT BY APPLICANT			LICANT	First Named Inventor	Betti-Berutto, Andrea	-
				Group Art Unit	2817	
(use as many sheets as necessary)			essary)	Examiner Name		
Sheet	1	of	2	Attorney Docket Number	021290-000100US	

U.S. PATENT DOCUMENTS					
Examiner Initials *	Cite No.1	U.S. Patent Document Kind Code ² (if known)	 -	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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INICO		ON DIG	OL OOUDE	Application Number		
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STATEMENT BY APPLICANT			PPLICANT	First Named Inventor	Betti-Berutto, Andrea	
				Group Art Unit	2817	
(use as many sheets as necessary)			necessary)	Examiner Name		
Sheet	2	of	2	Attorney Docket Number	021290-000100US	

OTHER PRIOR ART NON PATENT LITERATURE DOCUMENTS					
Examiner Initials *	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²		
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